## NSN 5961-01-026-2006

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View Online at https://aerobasegroup.com/nsn/5961-01-026-2006 **Inclosure Material:** Metal **Overall Length:** 1.266 inches **Overall Height:** 0.340 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 breakdown voltage, collector-to-base, emitter open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 7.00 amperes repetitive peak forward current blank and 2.00 amperes repetitive peak forward current **Power Rating Per Characteristic:** 90.0 watts small-signal input power, common-collector **Transfer Ratio:** 20.0 static forward current transfer ratio, common-emitter and 100.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure:** 

**Fiig:** A110a0

No

**Demilitarization:**